The NSF Nanoscale Science and Engineering Center for High-rate Nanomanufacturing www.nsec.neu.edu











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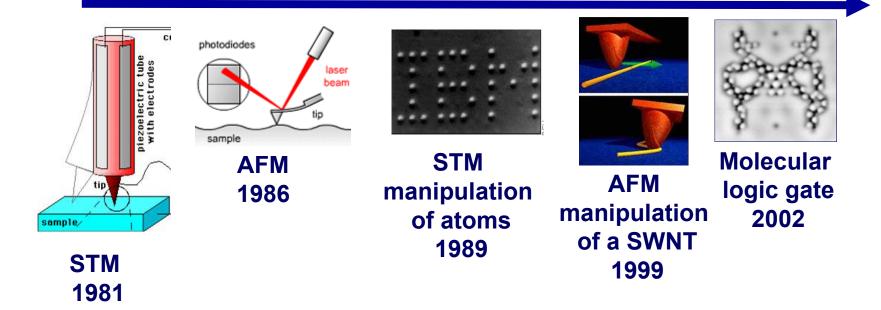
**Outreach Universities: Michigan State University** 

Collaboration and Outreach: Museum of Science-Boston, City College of New York, Hampton University, Rice University, ETH, University of Aachen, Hanyang University, Inje University, The Korean Center for Nanoscale Mechatronics and Manufacturing (CNMM), Taipei University, University of Hyogo

## Nanoscience

## Past and present:

#### **Manipulation of few atoms and SWNTs**



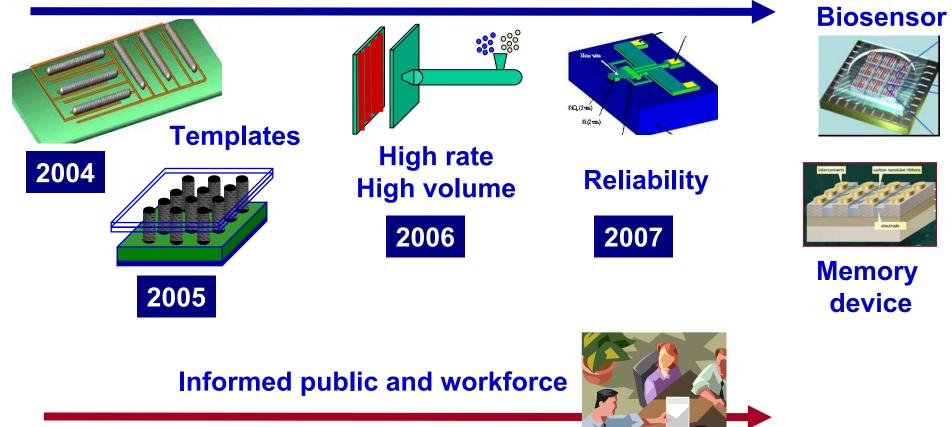


Source: IBM

# Nanomanufacturing

## Future:

#### **Manipulation of billions of atoms and SWNTs**



**Environmentally benign processes** 

# What are the Critical Barriers to Nanomanufacturing?

Barrier 1. How can we assemble and connect different nano-scale elements?

e.g., How do forces affect the orientation of nanoscale structures and interaction of surfaces? And how do we control these forces?

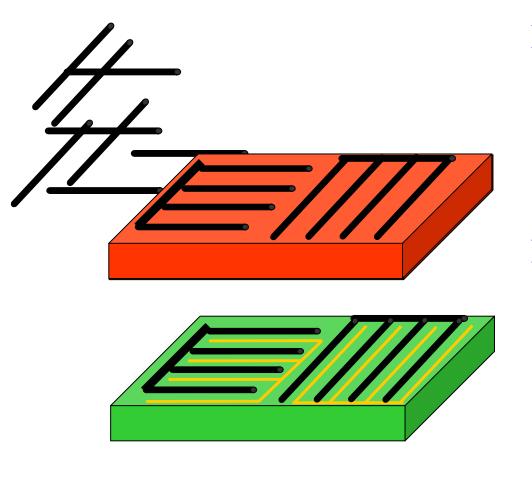
Barrier 2. How can we process nanoscale structures in a continuous or high rate manner? e.g., How do the interfacial behavior and forces required to assemble, detach, and transfer nanoelements differ at high rates and over large areas?

Barrier 3. How can we test for reliability? How can we efficiently detect and remove defects? e.g., How can we selectively remove defects without disturbing assembled nanoelements?

Barrier 4. Do nanoproducts and processes require new economic, environmental, and ethical/regulatory assessment and new sociallyaccepted values?

# **CHN Vision: Guided Self Assembly**

High-rate/High-volume Guided Self-Assembly of Nanoelements



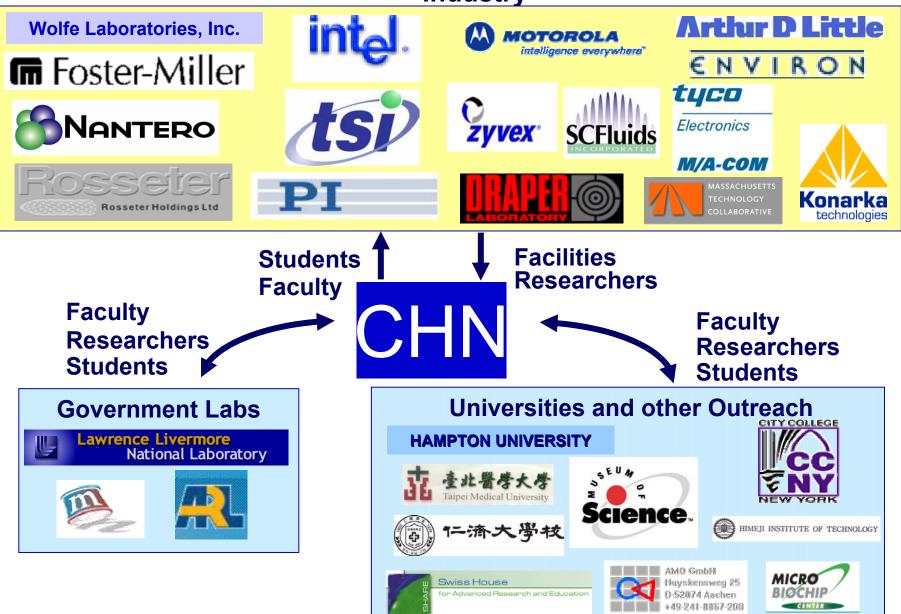
 State of the Art:
 Pure self-assembly produces regular patterns

- Challenge:
  - Nanotemplates enable guided self assembly

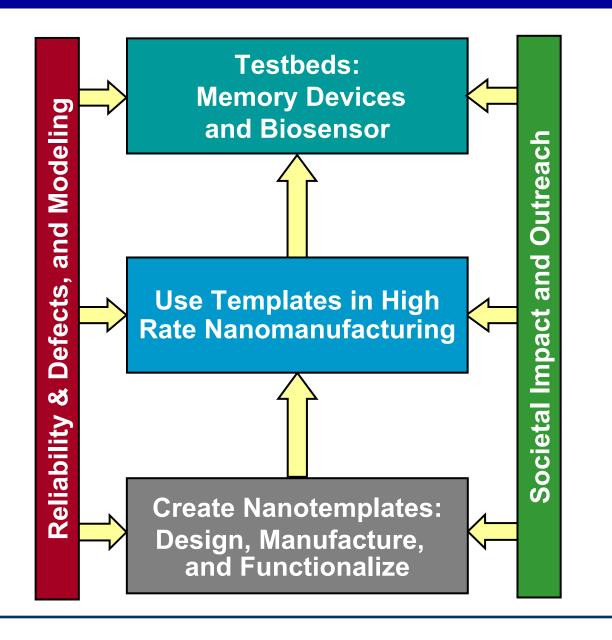


## **Partnerships**

Industry

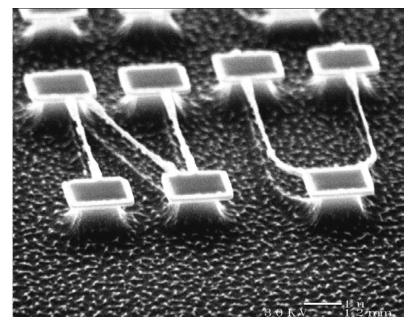


## **CHN's Path to Nanomanufacturing**

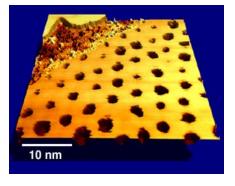


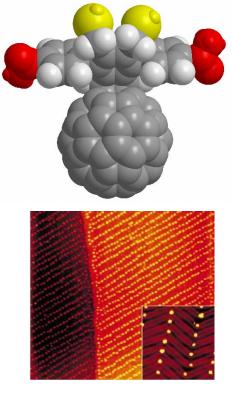
CHN

#### Nanotemplate Pattern Fabrication



AFM tip direction Writing direction Water meniscus Substrate

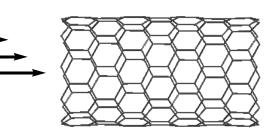




E-beam lithography: gold wires suspended over silicon (Northeastern U., 2004)



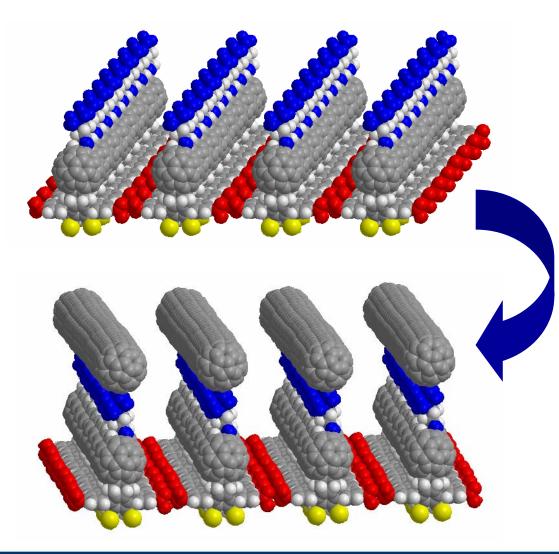




Controllable diameter Controllable length

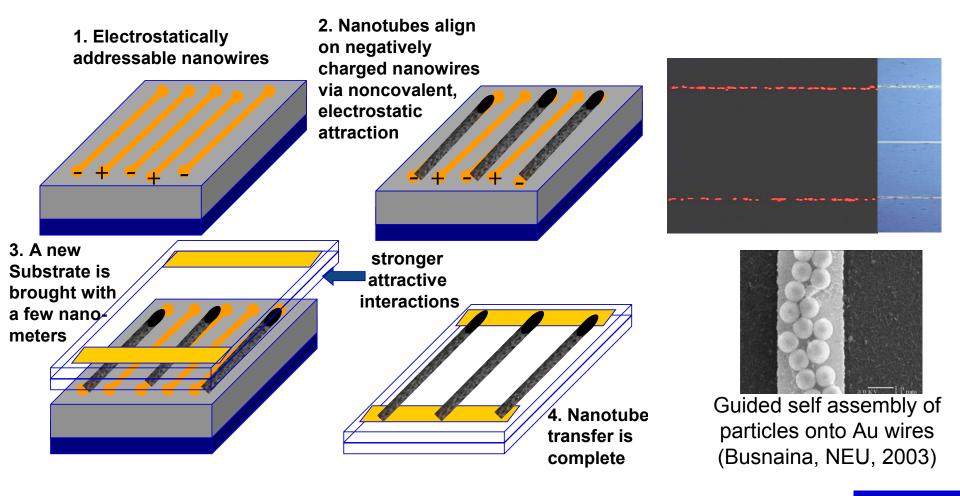


#### Challenge: Use the Nanotemplates for 2-D Assembly



Functionalizing the [60]fullerene array produces a nanotemplate that can be used to selectively bind nanoelements including single-walled carbon nanotubes

# Challenge: Use the Nanotemplates for 2-D Assembly



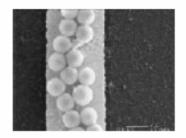


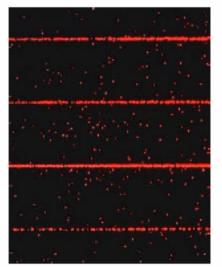
## Challenge: Use the Nanotemplates for 2-D Assembly

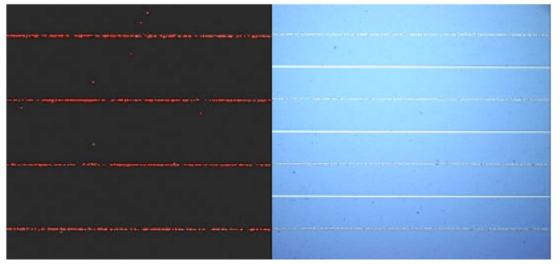
## **Controlled Assembly of Submicron Particles**

Gold surface has higher Hamaker Constant than Silicon surface and induces higher adhesion force on PSL particles.

Particles deposited anywhere else can be removed by flow rinse.

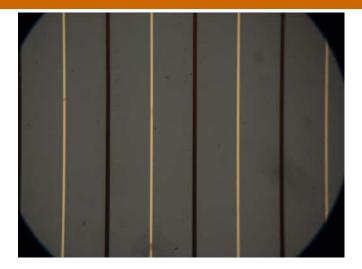




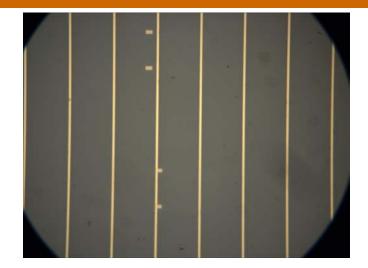


Assembly without cleaning Control Assembly with cleaning Control Selective removal of 800 nm particle on Nanotemplates

## Guided Assembly



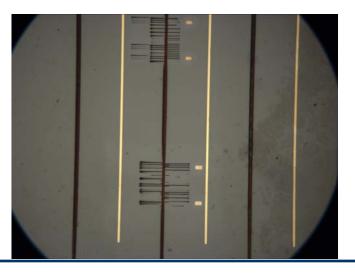
CNT on 2 micron Au wires, black wires are positive charged and yellow negative



50nm nanowires (nanotemplates) connected to 2 micron wires (nanowires cannot be seen in optical microscope)

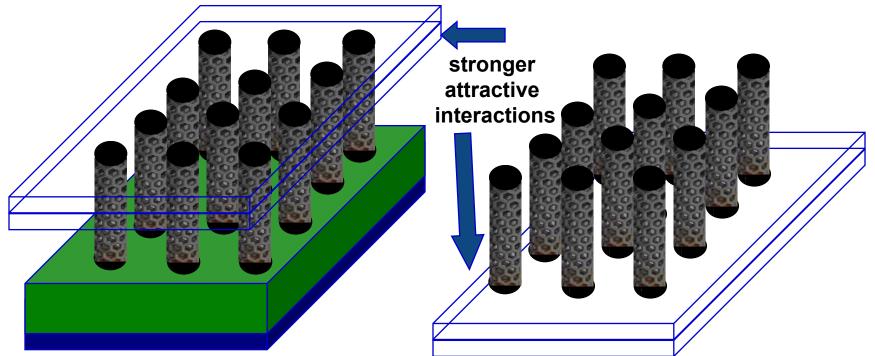
After CNT self-assembly, 50nm nanowires are covered with CNTs, which makes the nanowire wider and can be seen in optical microscope

Update





## **3-D Assembly of Nanotube Interconnects**



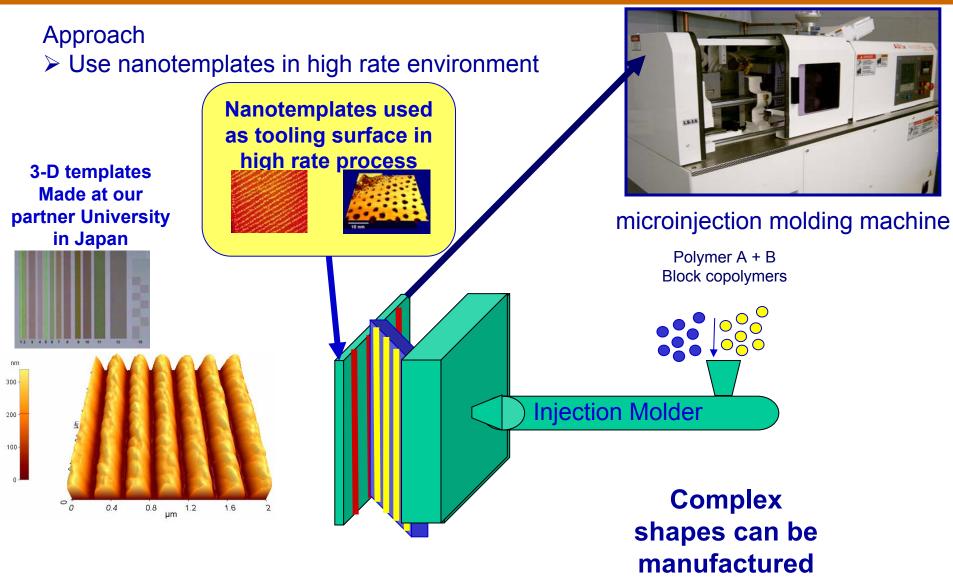
5. A new substrate with stronger attractive interactions is brought into contact



6. Nanotube transfer is complete

Possible applications: Nanotube interconnect and magnetic media

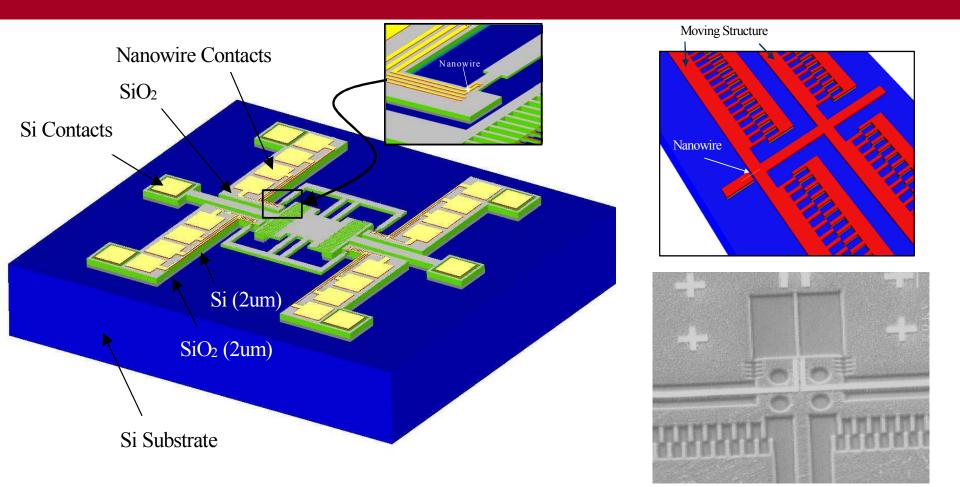
#### **Guided Self-Assembly of Polymer Melts at High Rates**







#### MEMs Nanoscale Characterization and Reliability Testbed



Innovative MEMS devices characterize nanowires (also nanotubes, nanorods and nanofibers) and conduct accelerated lifetime testing allowing rapid mechanical, electrical, and thermal cycling during UHV SPM observation

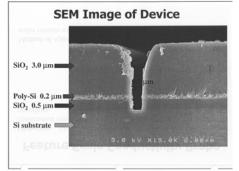
#### Defects in Nanomanufacturing

#### State of the Art (Semiconductor Industry)

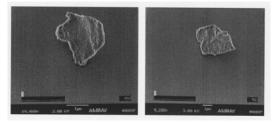
- Particulate, ionic, and organic contaminants
- Cleaning is applied over a large area
- Non selective removal
- Removal of defects: ~ 100 of 400 processing steps

#### **Challenges In Nanomanufacturing**

- Need to worry about the above and other defects
- Need selective impurity and defects removal (e.g., oxygen)
- Chemistry plays a larger role
- Need to understand the adhesion of surfaces, particles, and nanoelements in a variety of conditions and situations
- Cleaning nanostructures without destroying them



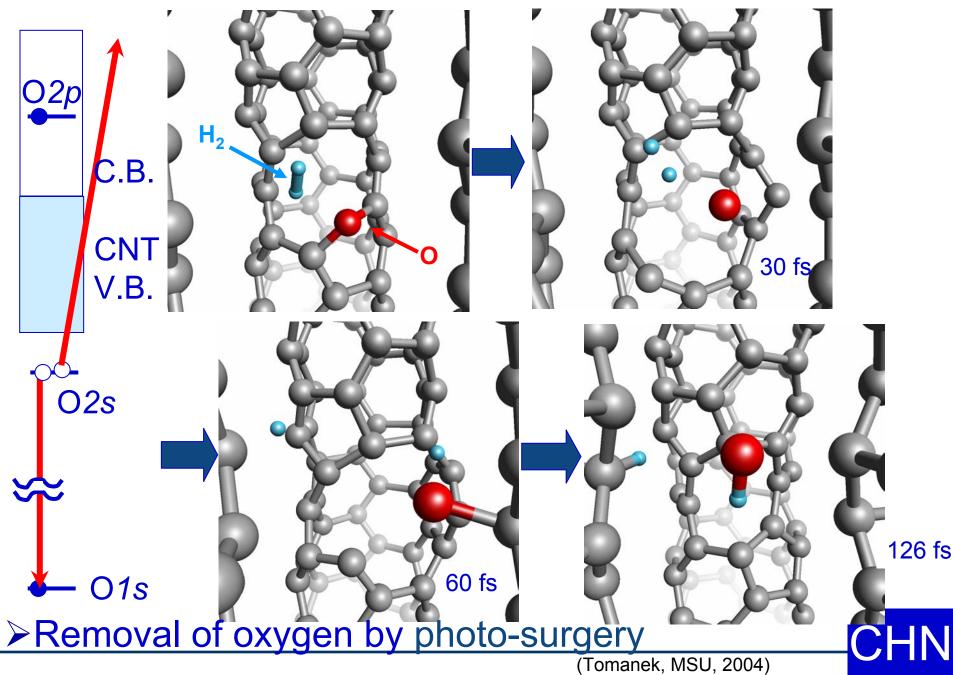
Photoresist particles trapped in submicron trench (Micron Technology)



Particles generated in a W CVD process (Busnaina, NEU, 1998)



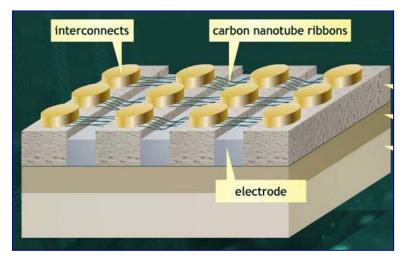
Auger decay following the O1s  $\rightarrow$  2p excitation (~520 eV)



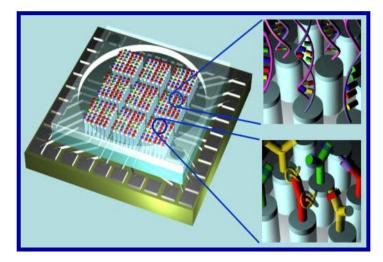
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## Proof of Concept Testbeds Research Drivers

True manufacturing success and product realization will not occur without strong industry partnership at inception



Nanotube Memory Device
Partner: Nantero
Making nanoelectronic devices using carbon nanotubes



#### **Biosensor**

Partner: Triton Systems

FDA testing on functionalized nanoparticles for cancer tumors with UML faculty



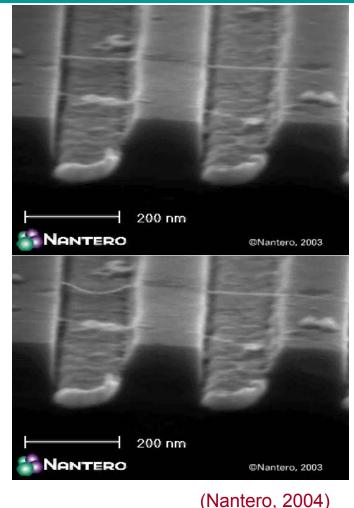
#### Use of Nanotemplates for Nanotube Memory Chip

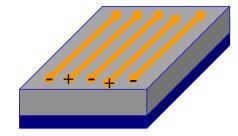
Ultimate scaling beyond CMOS to Tb/cm<sup>2</sup> requires breakthroughs:

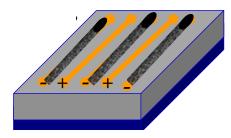
Large-scale precise, economic assembly of CNTs with:

- specific orientation and functionality
- with connection to the micro/macro level
- at high rate and volume

Nantero will use the developed nanotemplates with CMOS in a "hybrid" commercial testbed to reach ultimate scaling





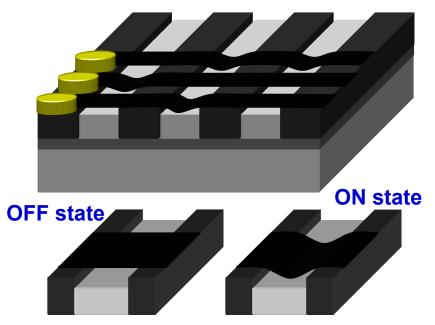


#### **High Density Memory Chip**

#### **Current process**

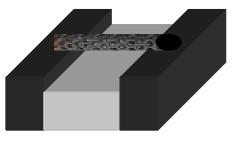
Uses conventional optical lithography to pattern carbon nanotube films

Switches are made from belts of nanotubes

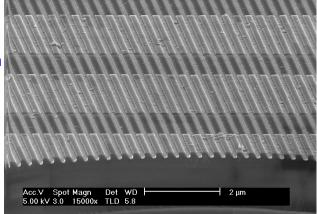


(Nantero, 2004)

# Nanotemplate will enable single CNT electromechanical switch

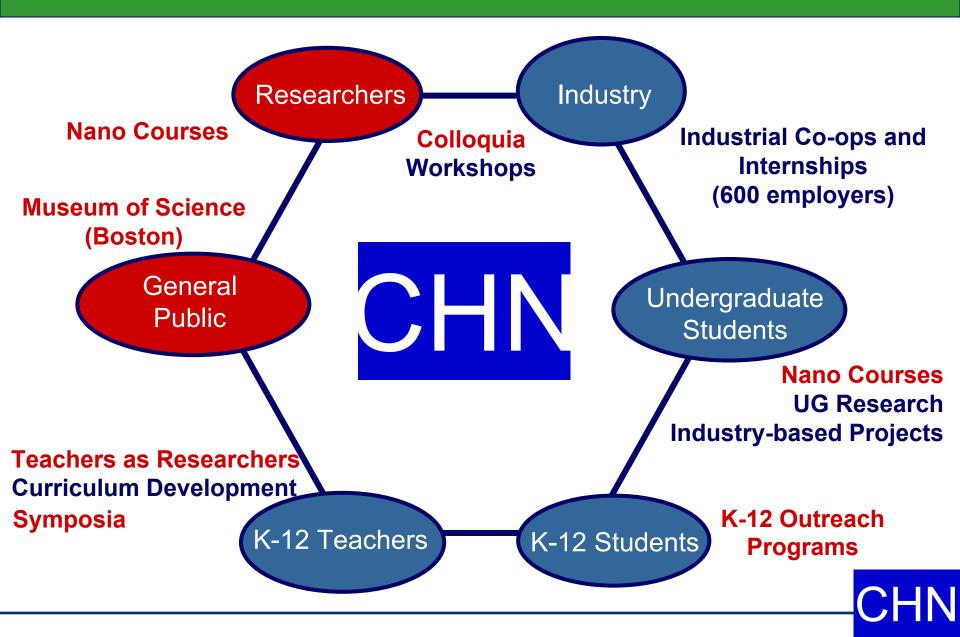


Electrodes (~100nm with 300 nm period)



(Nantero, 2004)

# **Education for Nanomanufacturing**



# George J. Kostas Nanoscale Technology and Manufacturing Center

Established through Mr. George J. Kostas generous gift, the Center Facility will be ready in February 2005.

The center will consist of three areas, fabrication, imaging and traditional labs. The first area consists of class 10 and 100 cleanrooms and includes capability for nanolithography (FESEM, Nanoimprint, etc,.), wet chemical processes. The second area is dedicated to imaging and characterization (SPM, STM, AFM and FESEM with a nanomanipulator), nanoparticle characterization (size and zeta potential) and surface energy analysis







# Summary

The Center for High-rate nanomanufacturing will enable the creation of commercial products by bridging the gap between scientific research and the creation of commercial products

The Center introduces novel science to enable high-rate/high-volume nanomanufacturing, such as:

- **1.** High-volume room-temperature uniform CNT synthesis
- 2. Fullerene nanowires
- 3. Nanotemplates for patterning polymers at high rates
- Environmental, economic, and societal impact will be addressed concurrently with the technical research tasks
- Strong partnerships with industry will accelerate commercialization
- Partnerships among universities, K-12 teachers and students, industry, and the Museum of Science (Boston) will deliver education in nanomanufacturing to the current and emerging workforce

